

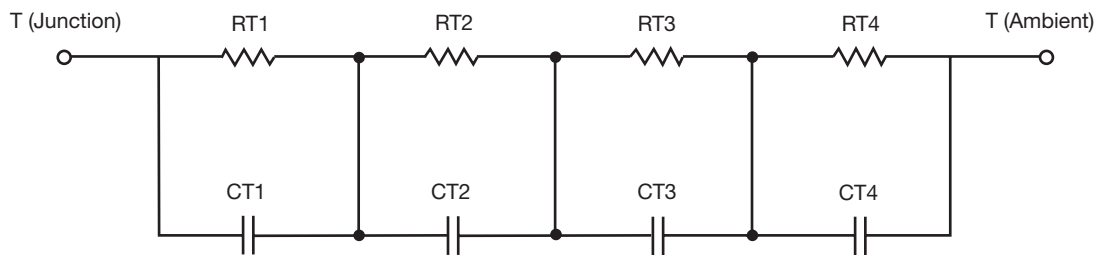
## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION

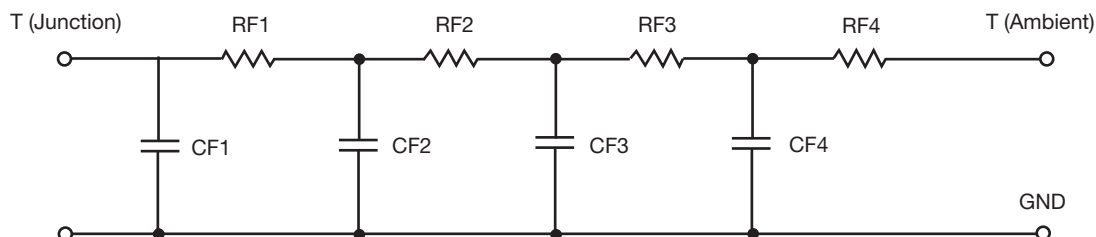


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	14.6969	735.2652 m	N/A
RT2	18.0407	819.5592 m	N/A
RT3	7.2956	800.2994 m	N/A
RT4	41.0302	1.6440	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	51.8800 m	665.0922 u	N/A
CT2	1.0096	13.1069 m	N/A
CT3	7.2823 m	3.8662 m	N/A
CT4	1.8828	5.9933 m	N/A

#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**

<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	7.3672	972.6592m	N/A
RF2	14.3928	1.7272	N/A
RF3	23.8535	1.2890	N/A
RF4	35.2782	21.6632m	N/A
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	5.2606m	493.3872u	N/A
CF2	29.6081m	1.0120m	N/A
CF3	439.7158m	6.8916m	N/A
CF4	1.3034	24.0056m	N/A

**Note**

N/A indicates not applicable

